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# HA13151, HA13152

14 W × 4-Channel BTL Power IC

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ADE-207-116  
1st. Edition

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## Description

The HA13151/HA13152 are high output and low distortion 4 ch BTL power IC designed for digital car audio.

At 13.2 V to 4 Ω load, this power IC provides output power 14 W with 10% distortion.

## Functions

- 4 ch BTL power amplifiers
- Built-in standby circuit
- Built-in muting circuit
- Built-in protection circuit (surge, T.S.D, and ASO)

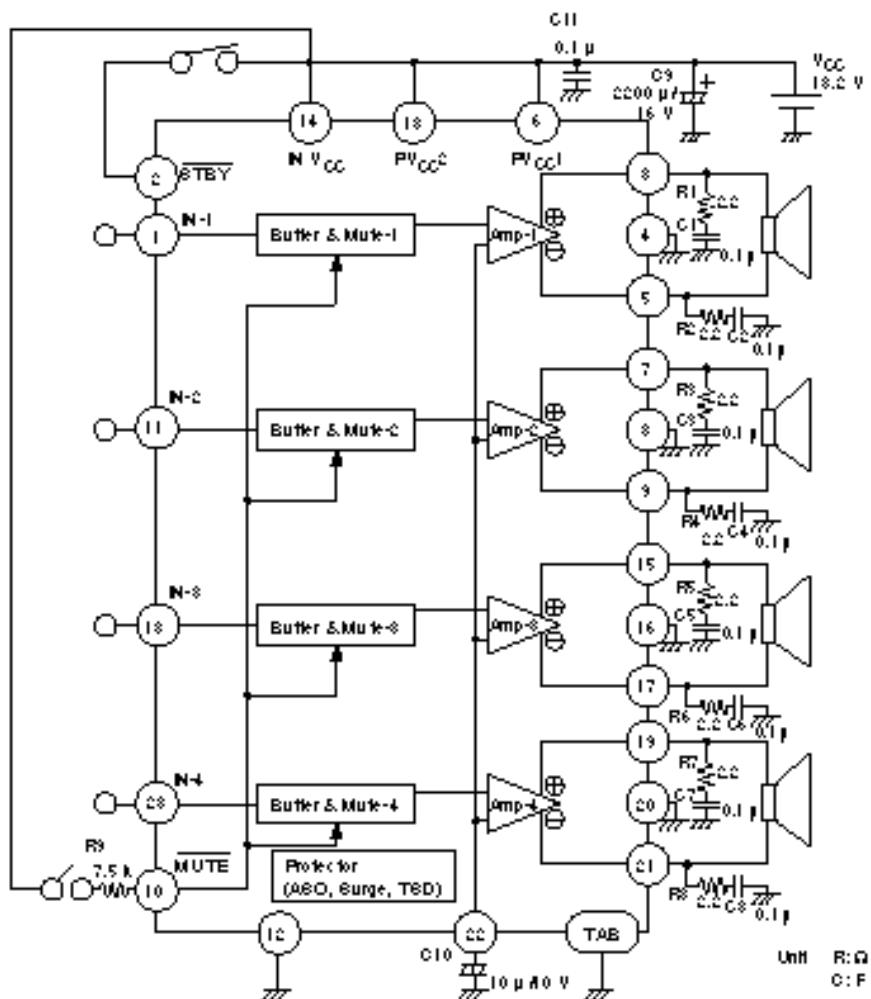
## Features

- Few external parts lead to compact set-area possibility
- Popping noise minimized
- Low output noise
- Built-in high reliability protection circuit



## HA13151, HA13152

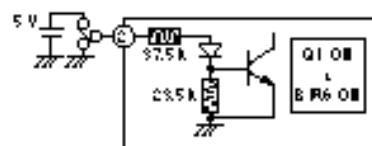
### Block Diagram



C1 to C8 should be polyester film capacitors with no secondary resonance (non-inductive) to assure stable operation.

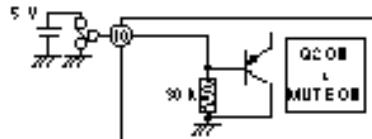
Notes:

1. Standby  
Power is turned on when a signal of 3.5 V or 0.05 mA is impressed at pin 2. When pin 2 is open or connected to GND, standby is turned on (output 1 off).



2. Muting

2. Muting  
Muting is turned off (output on) when a signal of 15 V or 0.1 mA is impressed at pin 10. When pin 10 is open or connected to GND, muting is turned on (output 1 off).



### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rating	Unit	Remarks
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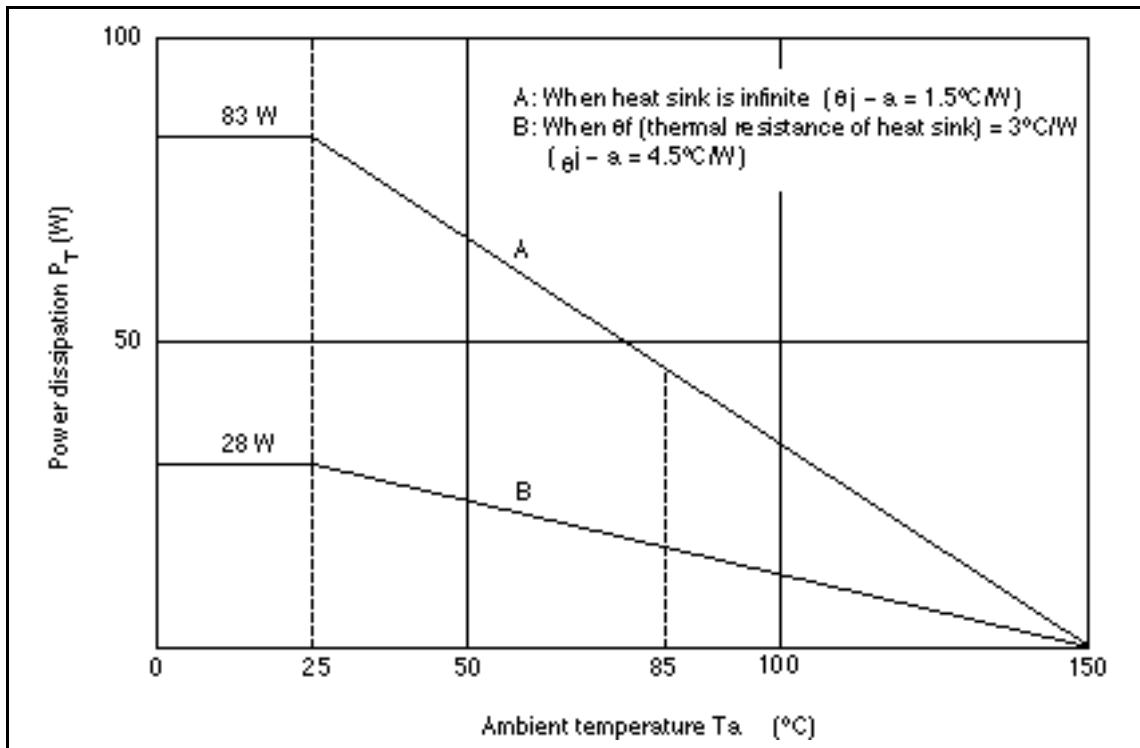
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Operating supply voltage	$V_{cc}$	18	V
Supply voltage when no signal <sup>*1</sup>	$V_{cc}$ (DC)	26	V
Peak supply voltage <sup>*2</sup>	$V_{cc}$ (PEAK)	50	V
Output current <sup>*3</sup>	$I_o$ (PEAK)	3	A
Power dissipation <sup>*4</sup>	$P_T$	83	W
Junction temperature	$T_j$	150	°C
Operating temperature	$T_{opr}$	-30 to +85	°C
Storage temperature	$T_{stg}$	-55 to +125	°C

- Notes:
1. Tolerance within 30 seconds
  2. Tolerance in surge pulse waveform
  3. Value per 1 channel
  4. Value when attached on the infinite heat sink plate at  $T_a = 25$  °C.

The derating curve is as shown in the graph below.



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**Electrical Characteristics** ( $V_{CC} = 13.2$  V,  $f = 1$  kHz,  $R_L = 4 \Omega$ ,  $R_g = 600 \Omega$ ,  $T_a = 25^\circ\text{C}$ )

### HA13151

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Quiescent current	$I_Q1$	—	270	—	mA	$V_{in} = 0$
Output offset voltage	$\Delta V_Q$	-300	0	+300	mV	
Gain	$G_V$	30.5	32	33.5	dB	
Gain difference between channels	$\Delta G_V$	-1.5	0	+1.5	dB	
Rated output power	$P_o$	—	14	—	W	$V_{CC} = 13.2$ V $THD = 10\%$ , $R_L = 4 \Omega$
Max output power	$P_{o\max}$	—	22	—	W	$V_{CC} = 13.7$ V $THD = \text{Max}$ , $R_L = 4 \Omega$
Total harmonic distortion	T.H.D.	—	0.05	—	%	$P_o = 3$ W
Output noise voltage	WBN	—	0.15	—	mVrms	$R_g = 0 \Omega$ $BW = 20$ to $20$ kHz
Ripple rejection	SVR	—	55	—	dB	$R_g = 600 \Omega$ , $f = 120$ Hz
Channel cross talk	C.T.	—	70	—	dB	$R_g = 600 \Omega$ $V_{out} = 0$ dBm
Input impedance	$R_{in}$	—	25	—	k $\Omega$	
Standby current	$I_Q2$	—	—	200	$\mu$ A	
Standby control voltage (high)	$V_{STH}$	3.5	—	$V_{CC}$	V	
Standby control voltage (low)	$V_{STL}$	0	—	1.5	V	
Muting control voltage (high)	$V_{MH}$	3.5	—	$V_{CC}$	V	
Muting control voltage (low)	$V_{ML}$	0	—	1.5	V	
Muting attenuation	ATTM	—	70	—	dB	$V_{out} = 0$ dBm

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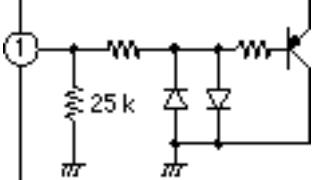
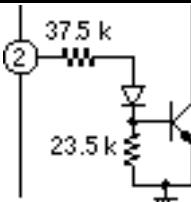
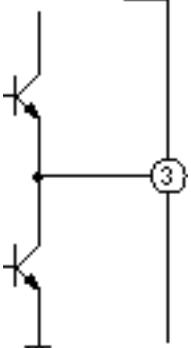
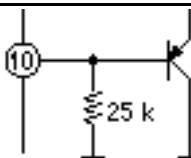
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### HA13152

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Quiescent current	$I_Q1$	—	270	—	mA	$V_{in} = 0$
Output offset voltage	$\Delta V_O$	-300	0	+300	mV	
Gain	$G_V$	38.5	40	41.5	dB	
Gain difference between channels	$\Delta G_V$	-1.5	0	+1.5	dB	
Rated output power	$P_o$	—	14	—	W	$V_{cc} = 13.2 \text{ V}$ $\text{THD} = 10\%$ , $R_L = 4 \Omega$
Max output power	$P_{o\max}$	—	22	—	W	$V_{cc} = 13.7 \text{ V}$ $\text{THD} = \text{Max}$ , $R_L = 4 \Omega$
Total harmonic distortion	T.H.D.	—	0.05	—	%	$P_o = 3\%$
Output noise voltage	WBN	—	0.25	—	mVrms	$R_g = 0 \Omega$ $BW = 20 \text{ to } 20 \text{ kHz}$
Ripple rejection	SVR	—	45	—	dB	$R_g = 600 \Omega$ , $f = 120 \text{ Hz}$
Channel cross talk	C.T.	—	60	—	dB	$R_g = 600 \Omega$ $V_{out} = 0 \text{ dBm}$
Input impedance	$R_{in}$	—	25	—	k $\Omega$	
Standby current	$I_{o2}$	—	—	200	$\mu\text{A}$	
Standby control voltage (high)	$V_{sth}$	3.5	—	$V_{cc}$	V	
Standby control voltage (low)	$V_{stl}$	0	—	1.5	V	
Muting control voltage (high)	$V_{mh}$	3.5	—	$V_{cc}$	V	
Muting control voltage (low)	$V_{ml}$	0	—	1.5	V	
Muting attenuation	ATTM	—	60	—	dB	$V_{out} = 0 \text{ dBm}$

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### Pin Explanation

Pin No.	Symbol	Functions	Input Impedance	DC Voltage	Equivalence Circuit
1	IN1	CH1 INPUT	25 kΩ (Typ)	0 V	
11	IN2	CH2 INPUT			
13	IN3	CH3 INPUT			
23	IN4	CH4 INPUT			
2	STBY	Standby control	90 kΩ (at Trs. cutoff)	—	
3	OUT1 +	CH1 OUTPUT	—	V <sub>cc</sub> /2	
5	OUT1 -				
7	OUT2 +	CH2 OUTPUT			
9	OUT2 -				
15	OUT3 +	CH3 OUTPUT			
17	OUT3 -				
19	OUT4 +	CH4 OUTPUT			
21	OUT4 -				
10	MUTE	Muting control	25 kΩ (Typ)	—	

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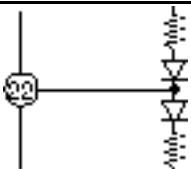
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### **Pin Explanation (cont)**

<b>Pin No.</b>	<b>Symbol</b>	<b>Functions</b>	<b>Input Impedance</b>	<b>DC Voltage</b>	<b>Equivalence Circuit</b>
22	RIPPLE	Bias stability	—	$V_{cc}/2$	
6	PV <sub>cc</sub> 1	Power of output stage	—	$V_{cc}$	—
18	PV <sub>cc</sub> 2				—
14	INV <sub>cc</sub>	Power of input stage	—	$V_{cc}$	—
4	CH1 GND	CH1 power GND	—	—	—
8	CH2 GND	CH2 power GND			
16	CH3 GND	CH3 power GND			
20	CH4 GND	CH4 power GND			
12	IN GND	Input signal GND	—	—	—

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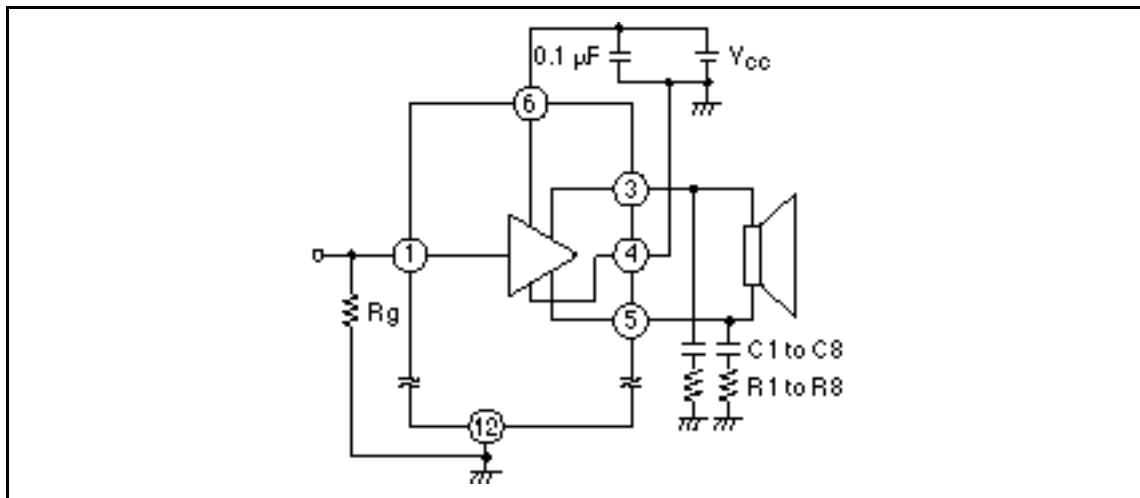
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### **Point of Application Board Design**

#### **1. Notes on Application Board's Pattern Design**

- For increasing stability, the connected line of V<sub>CC</sub> and OUTGND is better to be made wider and lower impedance.
- For increasing stability, it is better to place the capacitor between V<sub>CC</sub> and GND (0.1 µF) close to IC.
- For increasing stability, it is better to place C1 to C8 and R1 to R8, which are for stopping oscillation, close to IC.
- It is better to place the grounding of resistor (Rg), between input line and ground, close to INGND (Pin 12) because if OUTGND is connected to the line between Rg and INGND, THD will become worse due to current from OUTGND.



**Figure 1 Notes on Application Board's Pattern Design**

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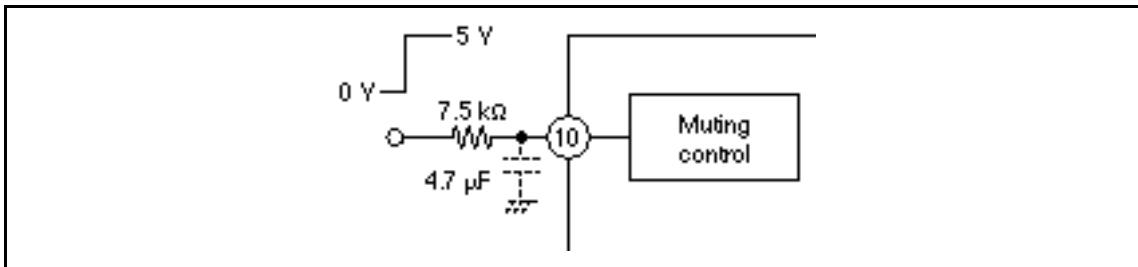
### **2. How to Reduce the Popping Noise by Muting Circuit**

At normal operating circuit, Muting circuit operates at high speed under 1  $\mu$ s.

In case popping noise becomes a problem, it is possible to reduce the popping noise by connecting capacitor, which determines the switching time constant, between pin 10 and GND. (Following figure 2)

We recommend value of capacitor greater than 1  $\mu$ F.

Also transitional popping noise can be reduced sharply by muting before  $V_{CC}$  and Standby are ON/OFF.

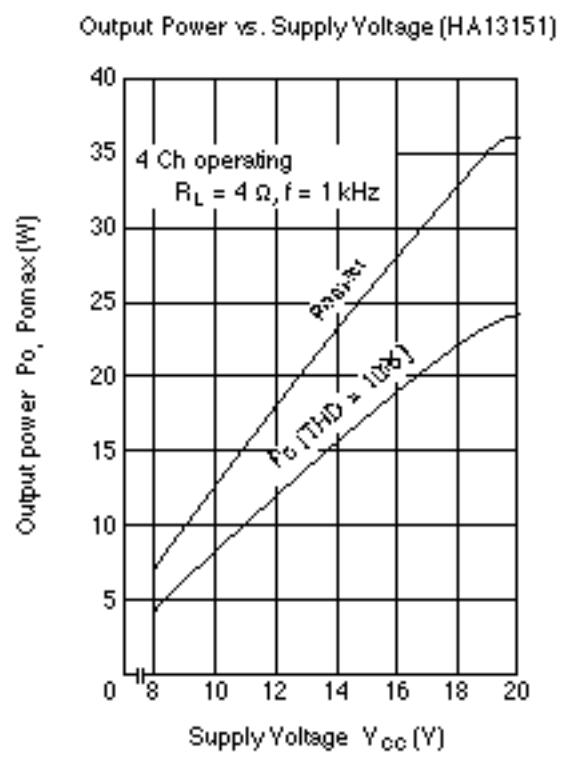
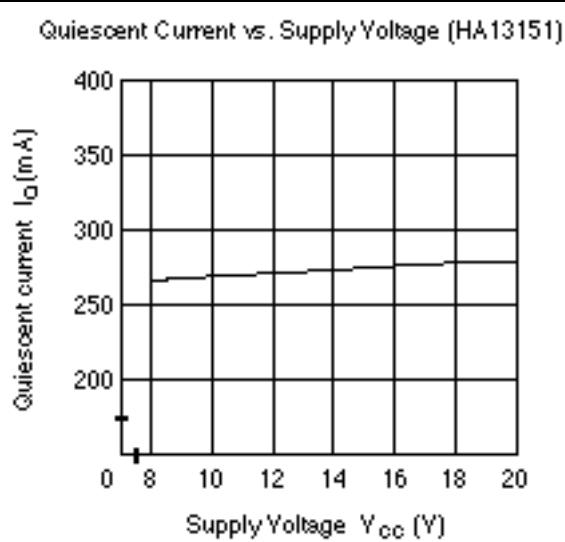


**Figure 2 How to use Muting Circuit**

**Table 1 Muting ON/OFF Time**

<b>C (<math>\mu</math>F)</b>	<b>ON Time</b>	<b>OFF Time</b>
nothing	under 1 $\mu$ s	under 1 $\mu$ s
0.47	2 ms	2 ms
4.7	19 ms	19 ms

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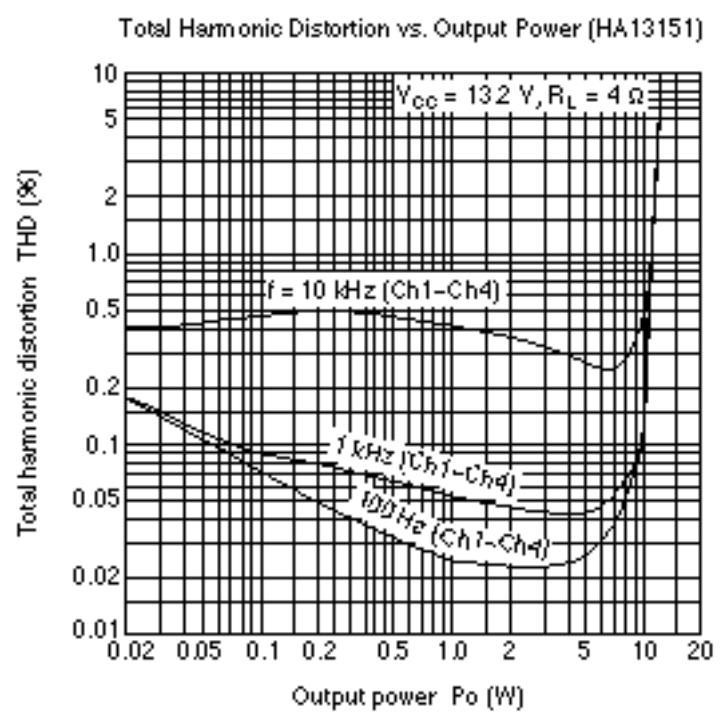
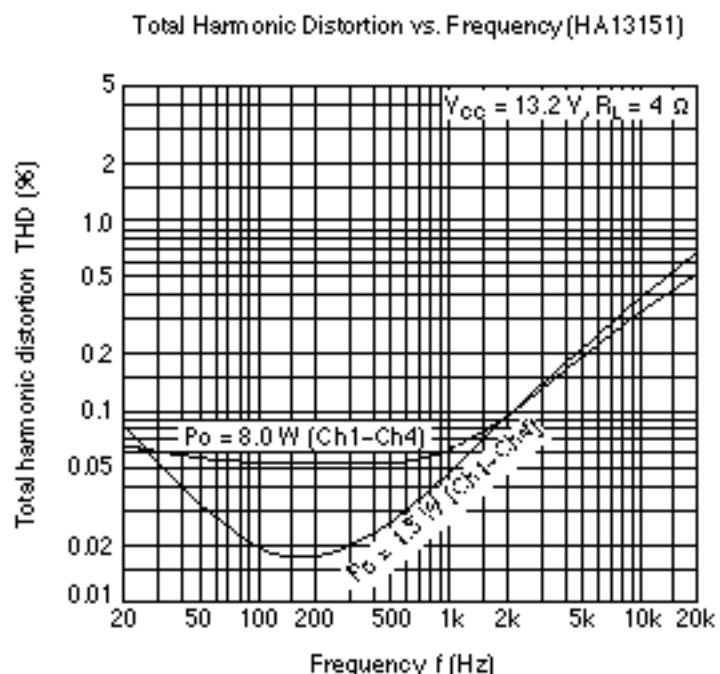


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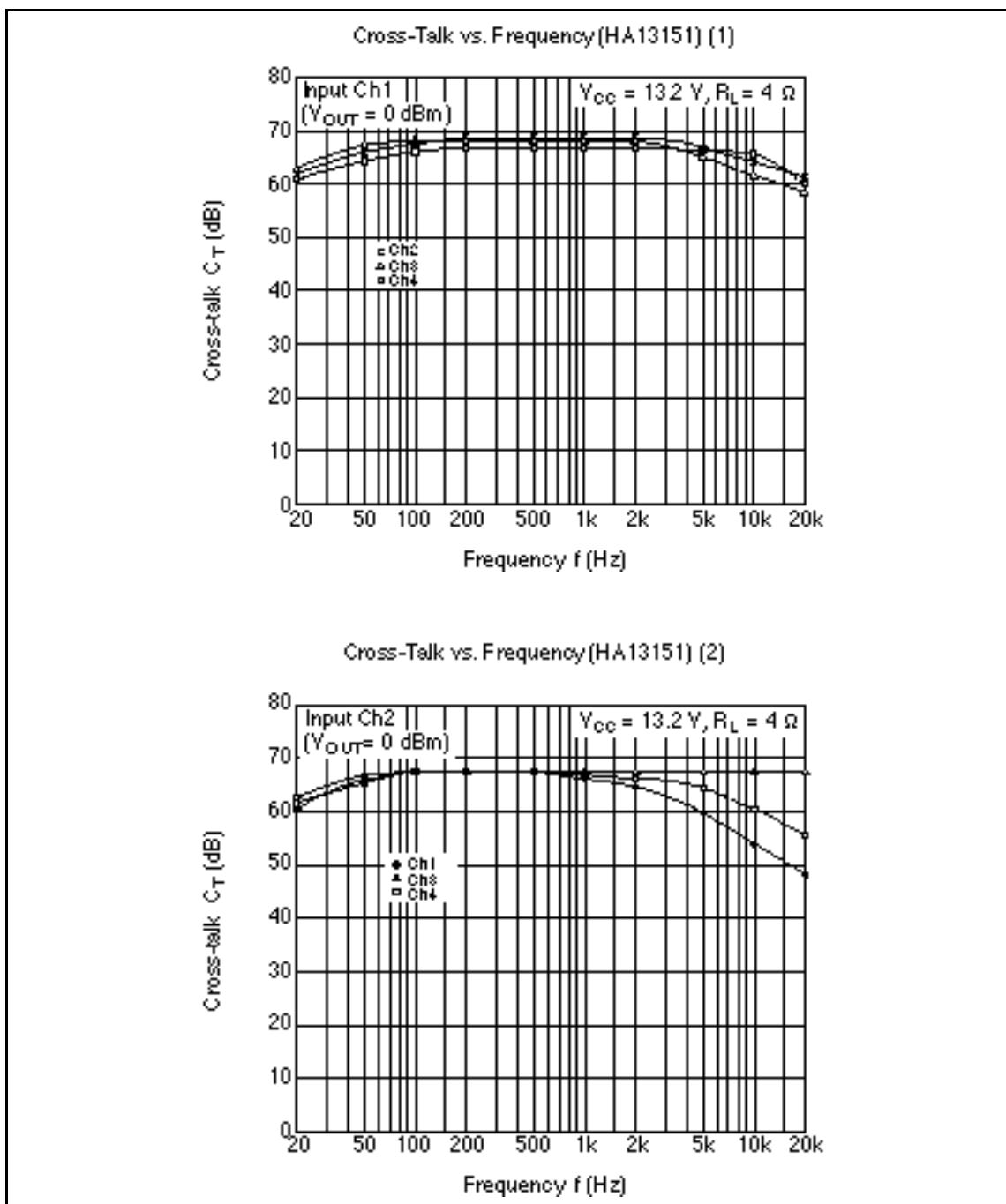
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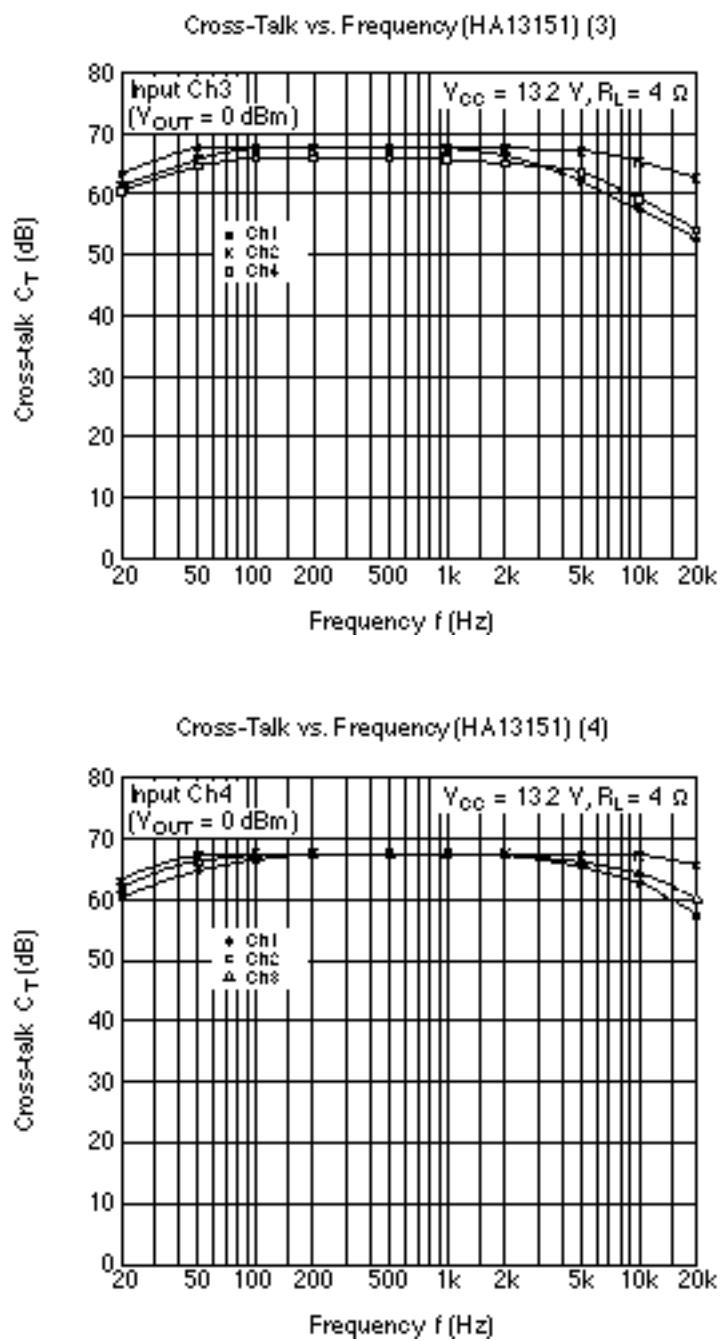


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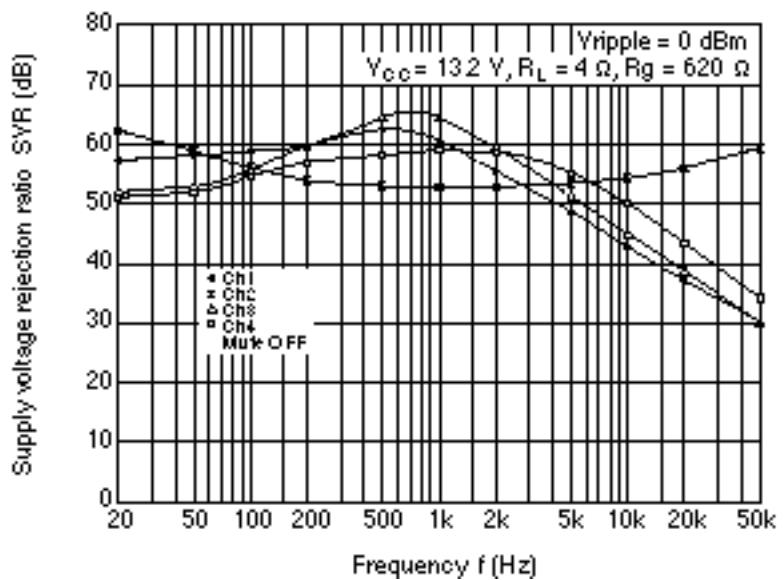
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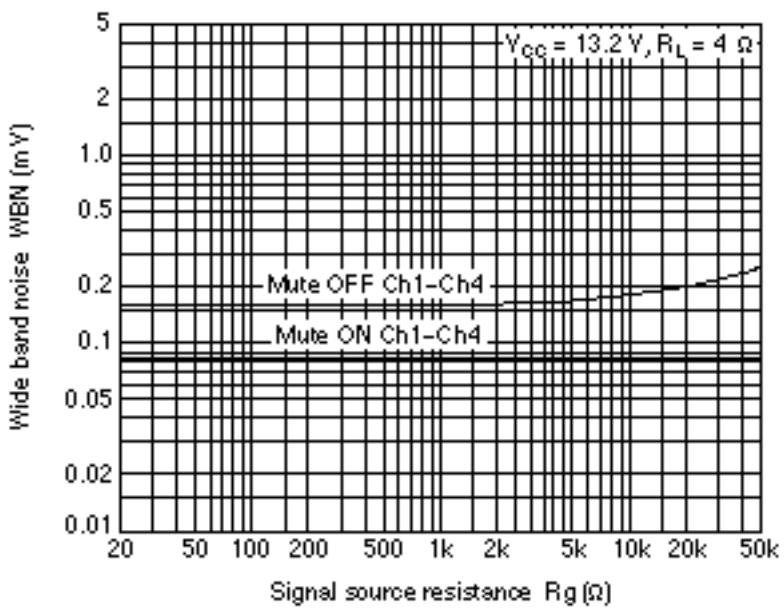


## HA13151, HA13152

Supply Voltage Rejection Ratio vs. Frequency (HA13151)



Wide Band Noise vs. Signal Source Resistance (HA13151)

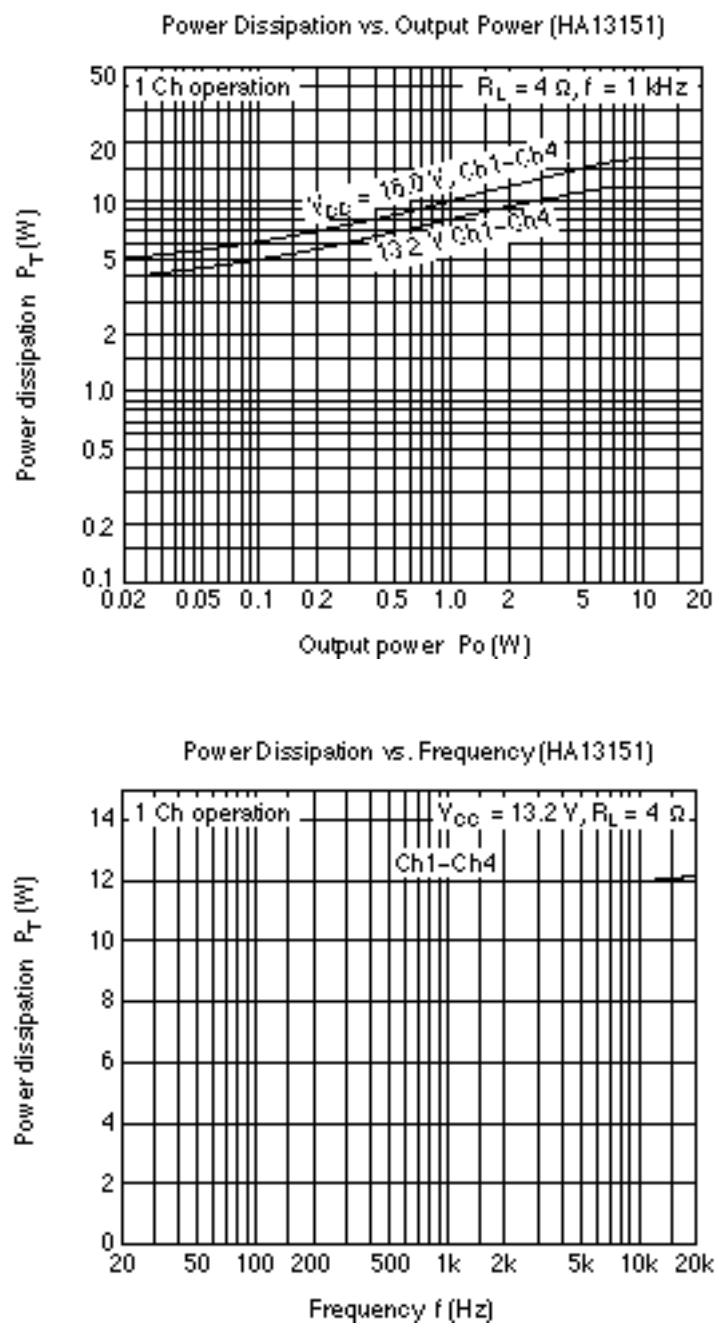


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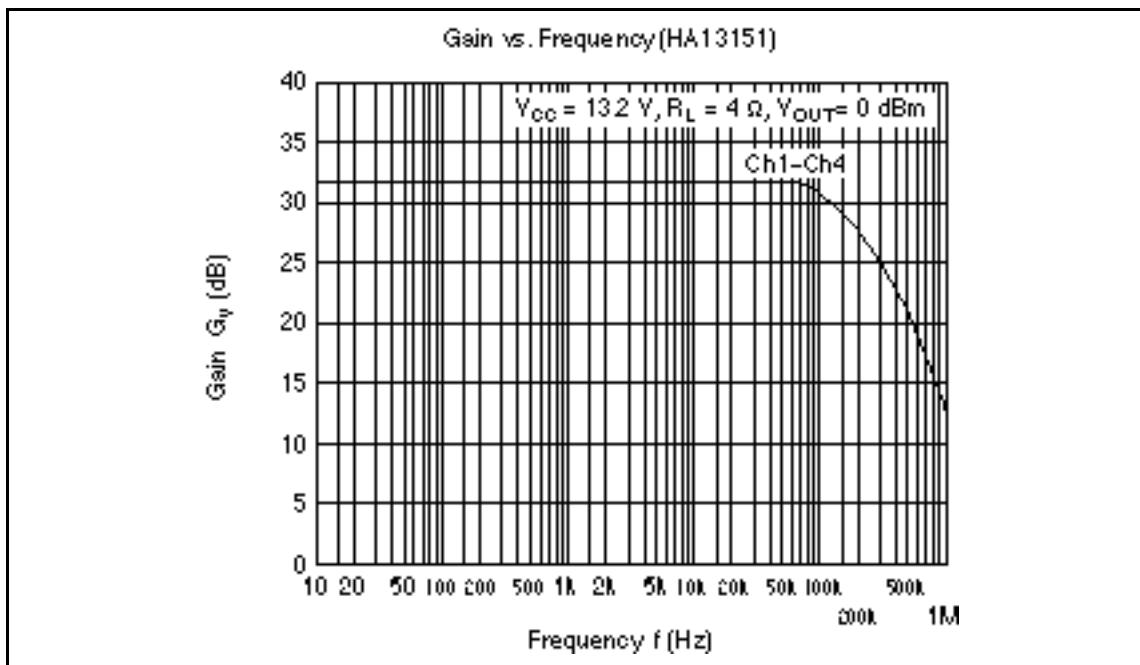
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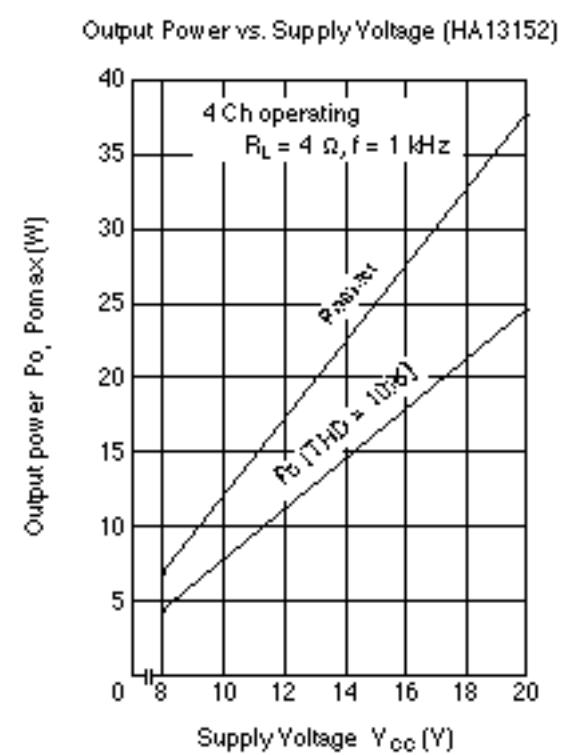
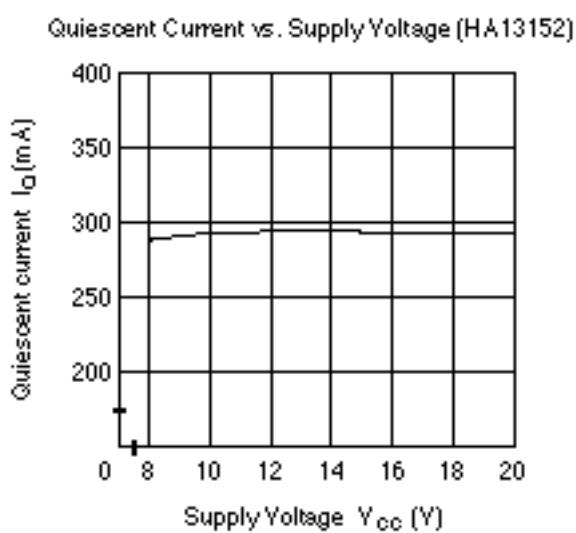


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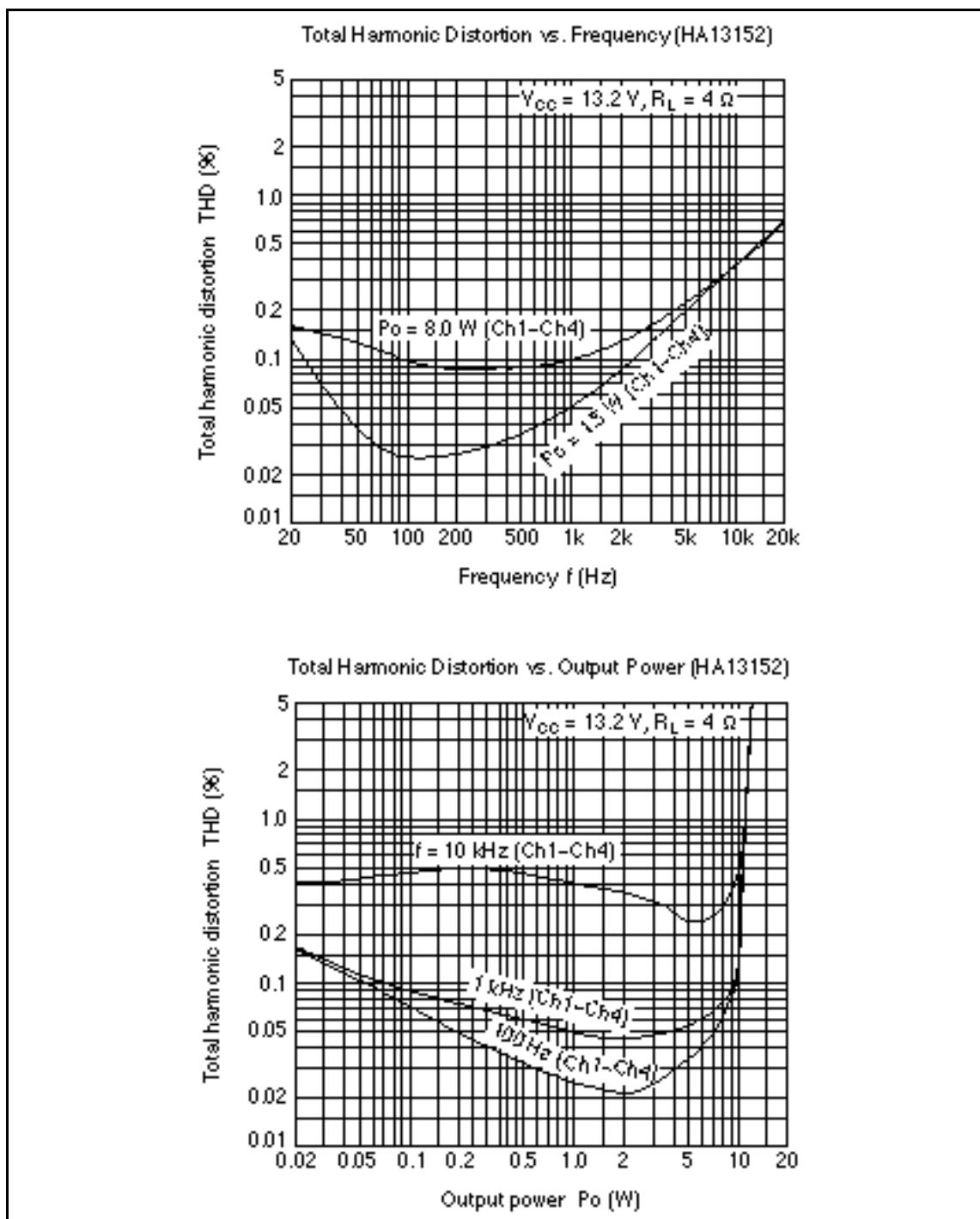
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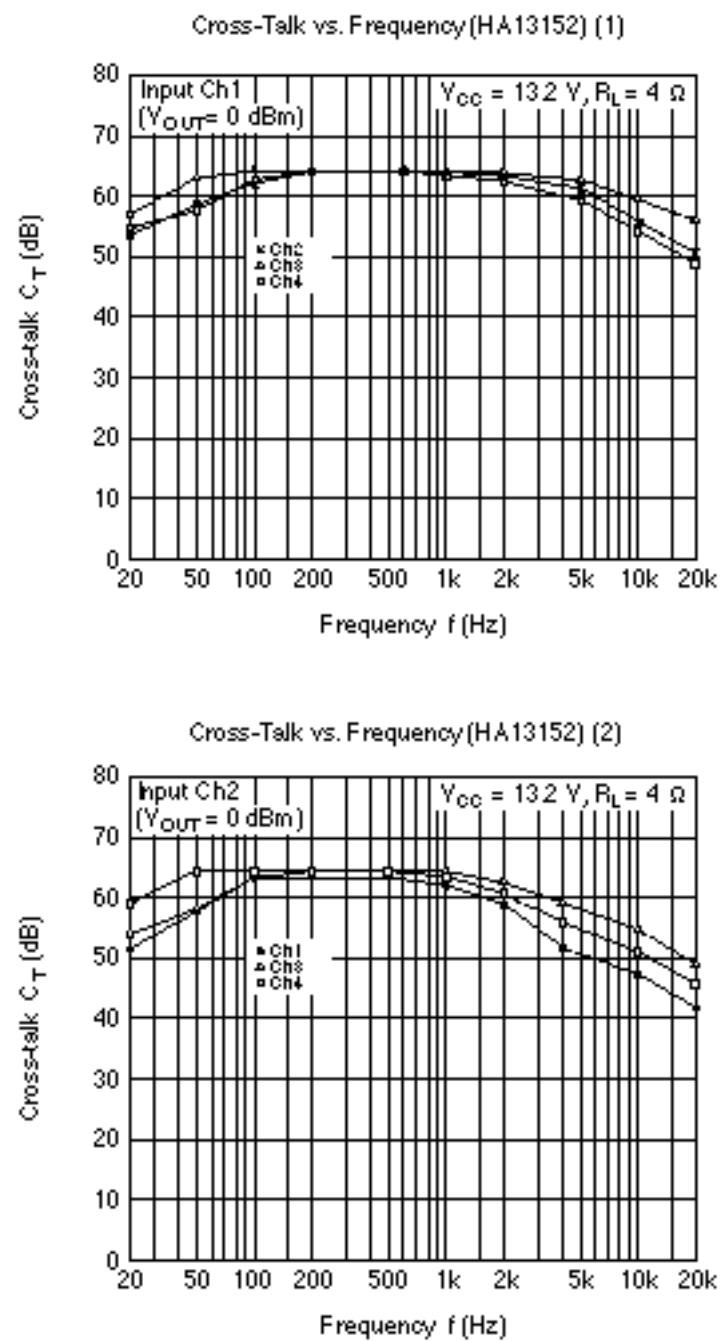


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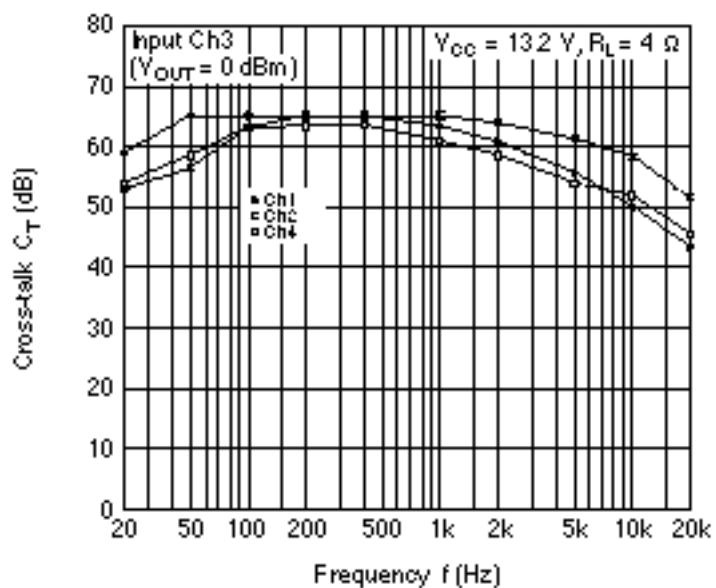


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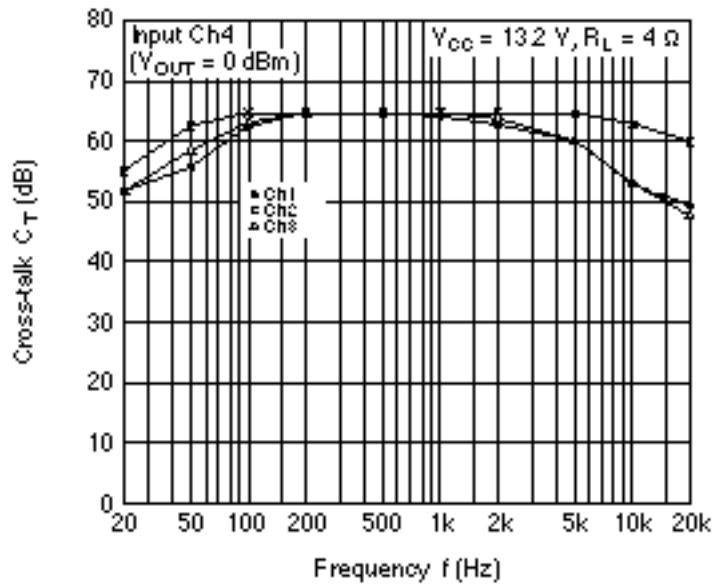
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Cross-Talk vs. Frequency (HA13152) (3)



Cross-Talk vs. Frequency (HA13152) (4)

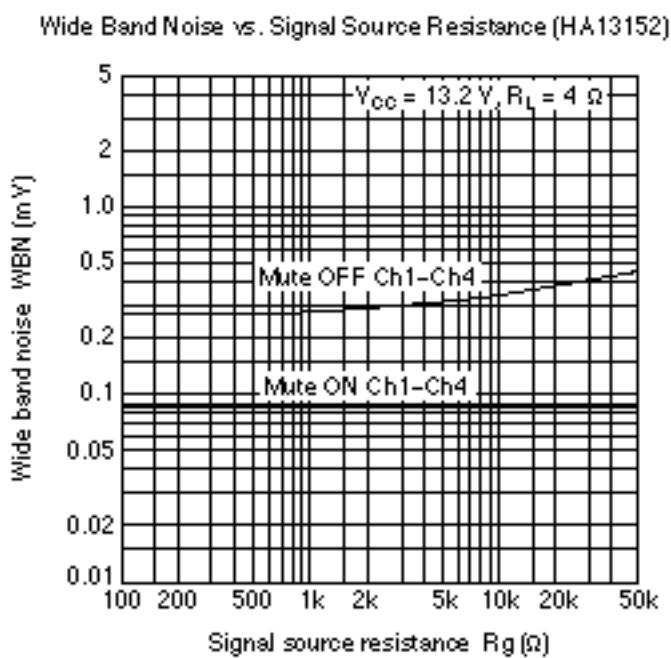
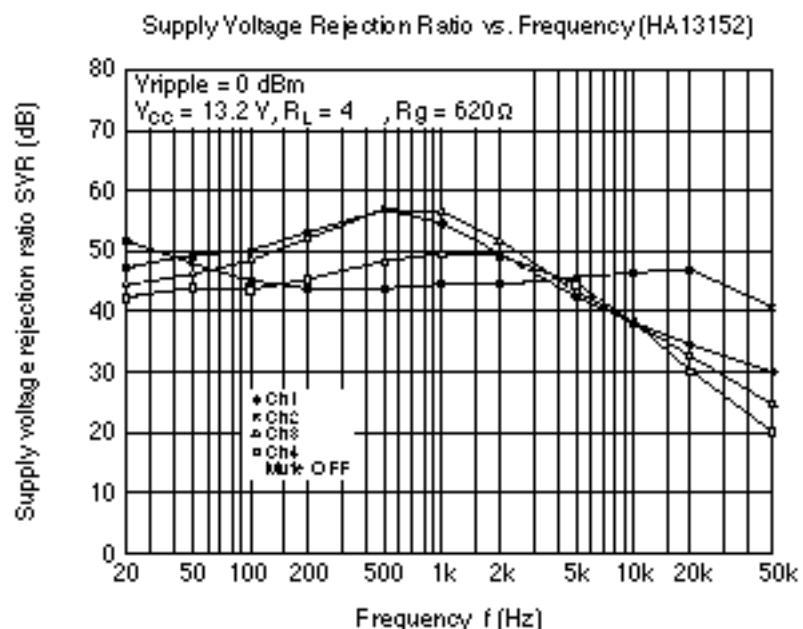


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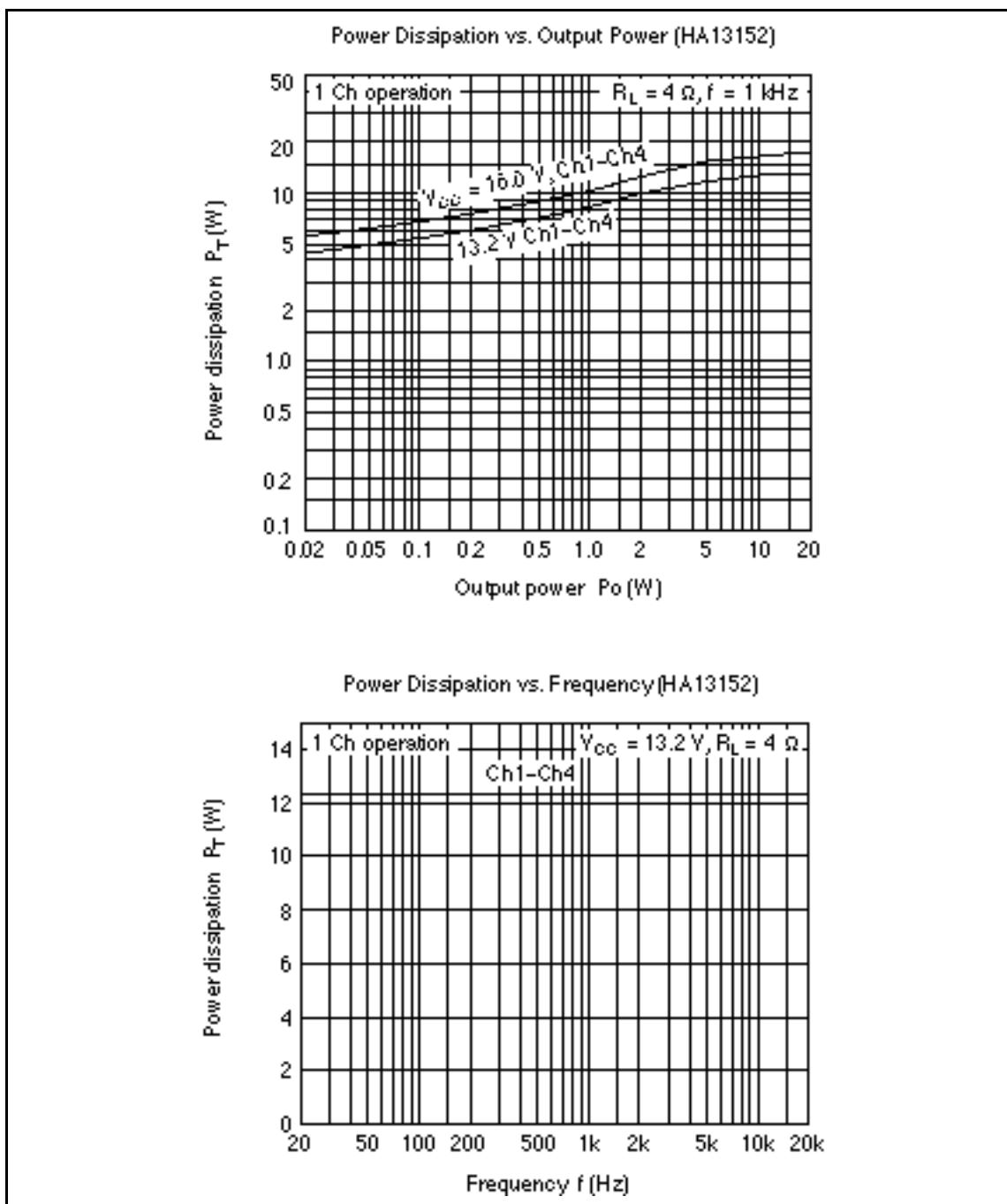
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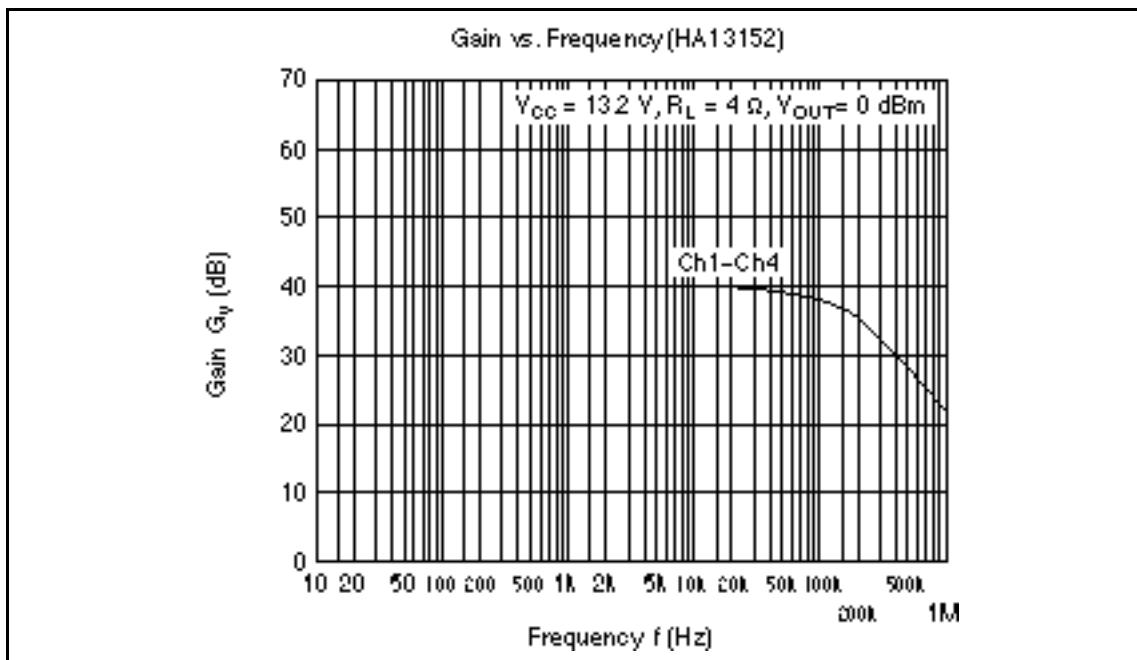


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